Low Noise Transistors PNP Silicon

MAXIMUM RATINGS

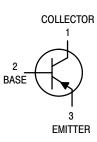
Rating	Symbol	BC559	BC560	Unit	
Collector–Emitter Voltage	V _{CEO}	-30	-45	Vdc	
Collector-Base Voltage	V _{CBO}	-30	-50	Vdc	
Emitter-Base Voltage	V _{EBO}	-5.0		Vdc	
Collector Current — Continuous	۱ _C	-100		mAdc	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0		mW mW/°C	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12		Watt mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150		°C	

BC559, B, C BC560C



THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction to Ambient	R_{\thetaJA}	200	°C/W
Thermal Resistance, Junction to Case	R_{\thetaJC}	83.3	°C/W



ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
	V _{(BR)CEO}	-30 -45			Vdc	
	V _{(BR)CBO}	30 50			Vdc	
Emitter–Base Breakdown Voltage $(I_E = -10 \ \mu Adc, I_C = 0)$	V _{(BR)EBO}	-5.0	—	—	Vdc	
Collector Cutoff Current $(V_{CB} = -30 \text{ Vdc}, I_E = 0)$ $(V_{CB} = -30 \text{ Vdc}, I_E = 0, T_A = +125^{\circ}\text{C})$	I _{CBO}			-15 -5.0	nAdc μAdc	
Emitter Cutoff Current ($V_{EB} = -4.0 \text{ Vdc}, I_C = 0$)	I _{EBO}	—	—	-15	nAdc	

BC559, B, C BC560C

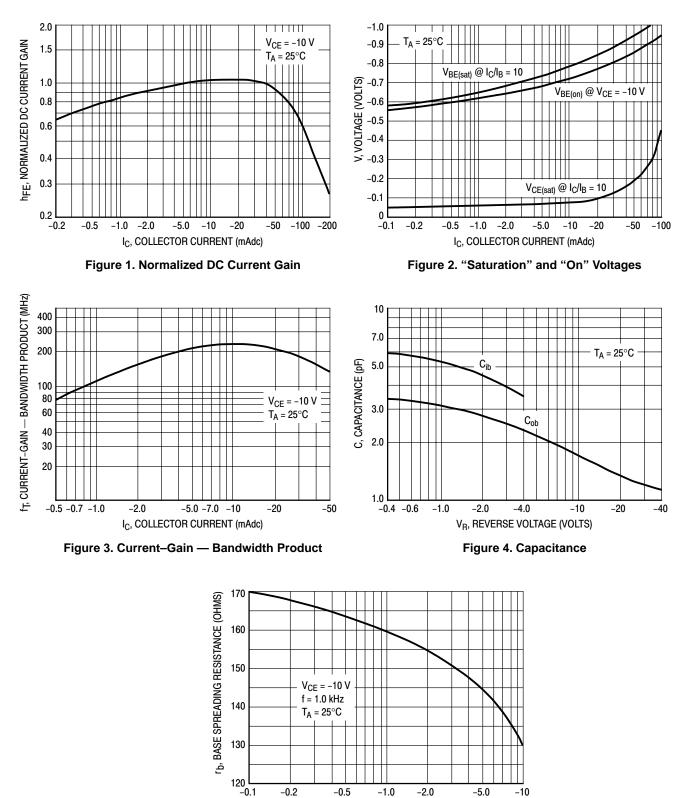
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS						
DC Current Gain ($I_C = -10 \mu Adc$, $V_{CE} = -5.0 Vdc$) ($I_C = -2.0 m Adc$, $V_{CE} = -5.0 Vdc$)	BC559B BC559C/560C BC559B BC559C/560C BC559	h _{FE}	100 100 180 380 120	150 270 290 500 —	 460 800 800	_
Collector–Emitter Saturation Voltage ($I_C = -10 \text{ mAdc}$, $I_B = -0.5 \text{ mAdc}$) ($I_C = -10 \text{ mAdc}$, $I_B = \text{see note 1}$) ($I_C = -100 \text{ mAdc}$, $I_B = -5.0 \text{ mAdc}$, see note 2)	V _{CE(sat)}		-0.075 -0.3 -0.25	-0.25 -0.6 	Vdc
Base–Emitter Saturation Voltage (I _C = –100 mAdc, I _B = –5.0 mAdc)		V _{BE(sat)}	—	-1.1	-	Vdc
$\begin{array}{l} \text{Base-Emitter On Voltage} \\ (I_{C} = -10 \; \mu \text{Adc}, \; \text{V}_{CE} = -5.0 \; \text{Vdc}) \\ (I_{C} = -100 \; \mu \text{Adc}, \; \text{V}_{CE} = -5.0 \; \text{Vdc}) \\ (I_{C} = -2.0 \; \text{mAdc}, \; \text{V}_{CE} = -5.0 \; \text{Vdc}) \end{array}$		V _{BE(on)}	 	-0.52 -0.55 -0.62	 	Vdc
SMALL-SIGNAL CHARACTERISTICS						
Current–Gain — Bandwidth Product (I _C = –10 mAdc, V _{CE} = –5.0 Vdc, f = 100 MH:	z)	fT	—	250	-	MHz
Collector–Base Capacitance ($V_{CB} = -10$ Vdc, $I_E = 0$, f = 1.0 MHz)		C _{cbo}	—	2.5	—	pF
Small–Signal Current Gain (I _C = –2.0 mAdc, V _{CE} = –5.0 V, f = 1.0 kHz)	BC559B BC559C/BC560C	h _{fe}	240 450	330 600	500 900	—
Noise Figure $(I_C = -200 \ \mu Adc, V_{CE} = -5.0 \ Vdc, R_S = 2.0 \ km cm^2)$ $(I_C = -200 \ \mu Adc, V_{CE} = -5.0 \ Vdc, R_S = 100 \ km^2)$		NF ₁ NF ₂	_	0.5 —	2.0 10	dB

NOTES:

1. I_B is value for which I_C = –11 mA at V_{CE} = –1.0 V. 2. Pulse test = 300 μs – Duty cycle = 2%.

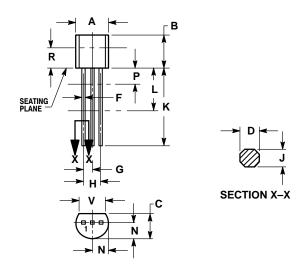
BC559, B, C BC560C



I_C, COLLECTOR CURRENT (mAdc) Figure 5. Base Spreading Resistance

PACKAGE DIMENSIONS

CASE 029-04 (TO-226AA) ISSUE AD



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.

 DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
V	0.135		3.43	

STYLE 17: PIN 1. COLLECTOR 2. BASE 3. EMITTER

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